

Vishay Semiconductors

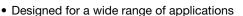
Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 50 A



PRODUCT SUMMARY			
I _{F(AV)}	50 A		
Package	DO-203AB (DO-5)		
Circuit configuration	Single diode		

FEATURES

• High surge current capability





- · Stud cathode and stud anode version
- Wire version available
- Low thermal resistance
- Designed and qualified for multiple level
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- Welding
- Any high voltage input rectification bridge

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
		50	Α		
I _{F(AV)}	T _C	128	°C		
I _{F(RMS)}		78	Α		
I _{FSM}	50 Hz	570	٨		
	60 Hz	595	Α		
l²t	50 Hz	1600	A ² s		
	60 Hz	1450	A-5		
V _{RRM}	Range	1400 to 1600	V		
T _J		-55 to 160	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE VOLTAGE NUMBER CODE VRRM, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA		
50PF(R)(W)	140	1400	1650	4.5	
30FF(h)(VV)	160	1600	1900	4.5	

50PF(R)...(W) High Voltage Series

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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average forward current		180° conduction, half sine wave		100° conduction half size ways		50	Α
at case temperature	I _{F(AV)}			128	°C		
Maximum RMS forward current	I _{F(RMS)}				78	Α	
		t = 10 ms	No voltage		570	A	
Maximum peak, one cycle forward,		t = 8.3 ms	reapplied		595		
non-repetitive surge current	IFSM	t = 10 ms	100 % V _{RRM} reapplied	Sinusoidal half wave, initial T _J = 150 °C	480		
		t = 8.3 ms			500		
	l ² t	t = 10 ms	No voltage		1600	- A ² s	
Maximum 12t for fraing		t = 8.3 ms	reapplied		1450		
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		1150		
		t = 8.3 ms	reapplied		1050		
Maximum I²√t for fusing	I ² √t	$t = 0.1 \text{ ms to } 10 \text{ ms, no voltage reapplied}$ 16 000 $A^2 \sqrt{s}$			A²√s		
Low level value of threshold voltage	V _{F(TO)}	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum 0.77 V			V		
Low level value of forward slope resistance	r _f	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum 4.30 m Ω			mΩ		
Maximum forward voltage drop	V_{FM}	I _{pk} = 125 A, T _J = 25 °C, t _p = 400 μs rectangular wave 1.50 V			V		

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to 160	°C	
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.51	K/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	K/VV	
Maximum allowable mounting torque (+0 %, -10 %)		Not lubricated thread, tighting on nut (1)	3.4 (30)	N · m (lbf · in)	
		Lubricated thread, tighting on nut (1)	2.3 (20)		
		Not lubricated thread, tighting on hexagon (2)	4.2 (37)		
		Lubricated thread, tighting on hexagon (2)	3.2 (28)		
Approximate weight			15.8	g	
Approximate weight			0.56	OZ.	
Case style		See dimensions - link at the end of datasheet DO-203AB (DO-5)		AB (DO-5)	

Notes

⁽¹⁾ Recommended for pass-through holes

⁽²⁾ Torque must be appliable only to hexagon and not to plastic structure, recommended for holed heatsink

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△R _{thJC} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.11	0.10				
120°	0.16	0.16				
90°	0.20	0.22	$T_J = T_J$ maximum	K/W		
60°	0.29	0.31				
30°	0.49	0.50				

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

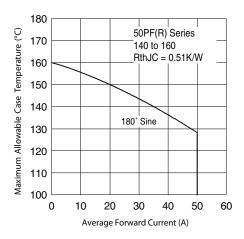


Fig. 1 - Current Ratings Characteristics

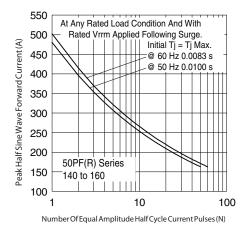


Fig. 2 - Maximum Non-Repetitive Surge Current

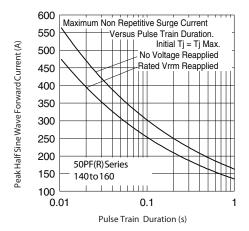


Fig. 3 - Maximum Non-Repetitive Surge Current

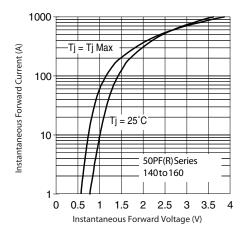


Fig. 4 - Forward Voltage Drop Characteristics

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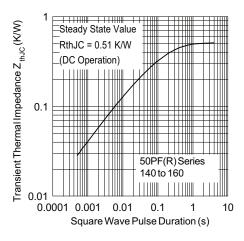
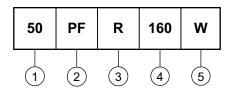


Fig. 5 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



- 1 50 = Standard device
- 2 PF = Plastic package
- 3 • None = Stud normal polarity (cathode to stud)
 - R = Stud reverse polarity (anode to stud)
 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- None = Standard terminal (see dimensions for 50PF(R)... - link at the end of datasheet)
 - W = Wire terminal (see dimensions for 50PF(R)...W - link at the end of datasheet)

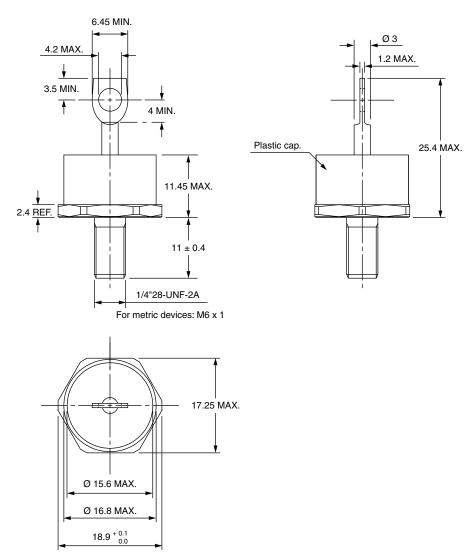
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95345	



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DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W) and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R) AND 95PF(R) SERIES in millimeters



Note

• For metric device please contact factory

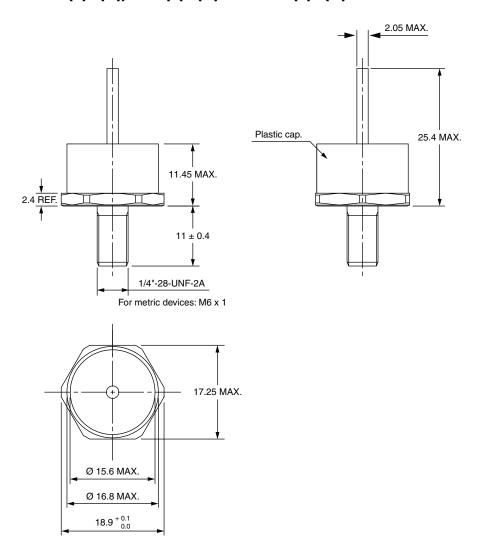
Outline Dimensions

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DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W) and 95PF(R)...(W) Series



DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W) AND 95PF(R)...(W) SERIES in millimeters



Note

• For metric device please contact factory

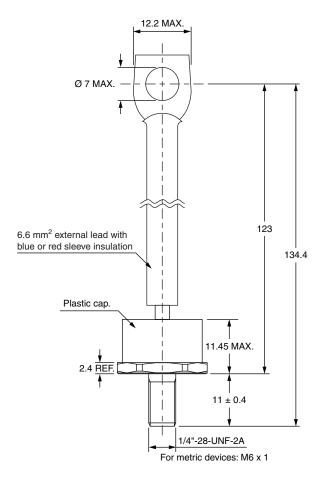
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DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W) and 95PF(R)...(W) Series

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DIMENSIONS FOR 52PF(R), 82PF(R) AND 97PF(R) SERIES in millimeters



Note

• For metric device please contact factory



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